

TO 3
CASE

30 Amp Center Tapped Silicon Integrated Rectifiers

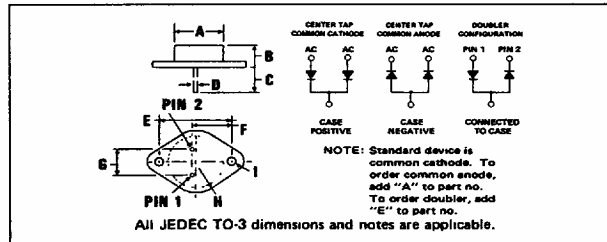
Controlled Avalanche Types with 250V,
450V, and 650V Minimum Avalanche Ratings

Non-Controlled Avalanche Types with
100V, 200V, 400V and 600V V_{RRM} Ratings

High Cycle Surge Current

Fast Recovery Types with 200 Nanosecond Maximum t_{rr}

LTR.	INCHES	MILLIMETERS
A	.73-.77 Dia.	18.54-19.56 Dia.
B	.323-.342	8.20-8.69
C	.40 Min.	10.16
D	.038-.043 Dia.	.97-1.09
E	1.180-1.194	29.97-30.33
F	.665-.675	16.89-17.15
G	.426-.440	10.82-11.18
H	.525R Max.	13.34R
I	.151-.161 Dia.	3.34-4.09



MAXIMUM RATINGS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

RATINGS	SYMBOL	CONTROLLED AVALANCHE			NON-CONTROLLED AVALANCHE				FAST RECOVERY TIME				UNITS
		R702	R704	R706	R711	R712	R714	R716	R711X	R712X	R714X	R716X	
Series Number													
DC Blocking Voltage	V_{RM}	200	400	600	100	200	400	600	100	200	400	600	Volts
Working Peak Reverse Voltage	V_{RRM}												
Peak Repetitive Reverse Voltage	V_{RRM}												
RMS Reverse Voltage	V_{RRMS}	140	280	420	70	140	280	420	70	140	280	420	Volts
Power Dissipation in V_{RRM} Region for 100 μ sec Square Wave (Per diode)	P_{RM}	1500			NA				NA				Watts
Continuous Power Dissipation in V_{RRM} Region at $T_C = 100^{\circ}\text{C}$ (Per diode)	P_R	4			NA				NA				Watts
Peak Surge Current, 1/2 Cycle at 60 Hz, (Non-Rep) and $T_C = 100^{\circ}\text{C}$ (Per diode) (Fig. 2)	I_{FSM}	300								150			Amps
Peak Surge Current, 1 sec at 60 Hz and $T_C = 100^{\circ}\text{C}$ (Per diode) (Fig. 2)	I_{FRM}	60								50			Amps
Avg. Forward Current at $T_C = 100^{\circ}\text{C}$ (Per diode)	I_O	15											Amps
Junction Operating and Storage Temperature Range	T_J, T_{STG}	- 65 to + 150											$^{\circ}\text{C}$
Fusing Data	I^2T	375							95				Amps ² -Sec.

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

CHARACTERISTICS	SYMBOL	CONTROLLED AVALANCHE			NON-CONTROLLED AVALANCHE				FAST RECOVERY TIME				UNITS	
Series Number		R702	R704	R706	R711	R712	R714	R716	R711X	R712X	R714X	R716X		
Minimum Avalanche Voltage	V _{BR}	250	450	650	NA				NA				Volts	
Maximum Avalanche Voltage	V _{BR}	700	900	1100	NA				NA				Volts	
Maximum Instantaneous Forward Voltage Drop (Per diode) at 15 Amps (Fig. 3)	V _{FM}	1.2								1.4				Volts
Maximum Reverse Current at Rated V _{RM} at T _C = 100°C	I _{RM}	1								5				mA
Maximum Reverse Recovery Time at I _F = 1A, I _F = 2A I _{RR} = 0.5 Amp	t _{rr}	NA								200				nsec
Maximum Thermal Resistance, Junction to Case	R _{θJC}					1.5								°C/W

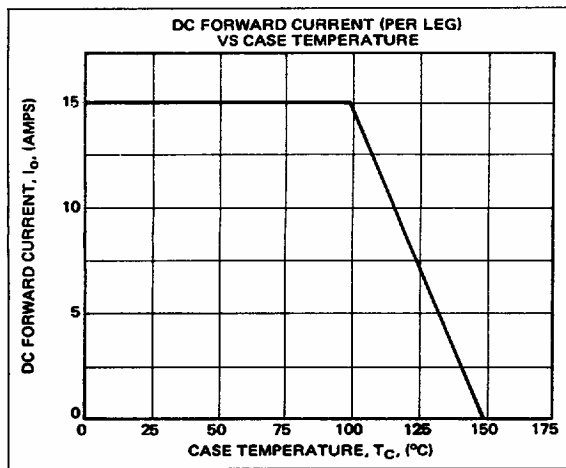


FIGURE 1

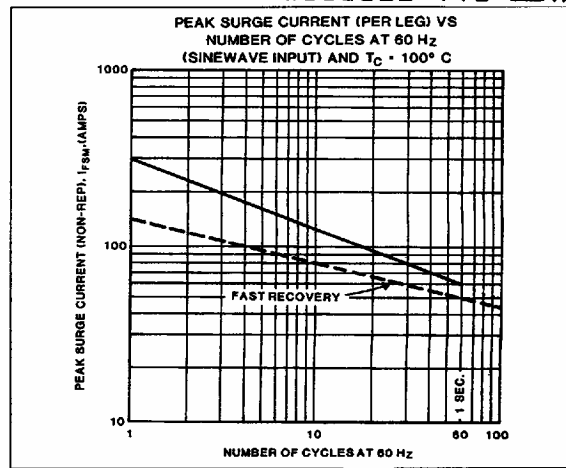


FIGURE 2

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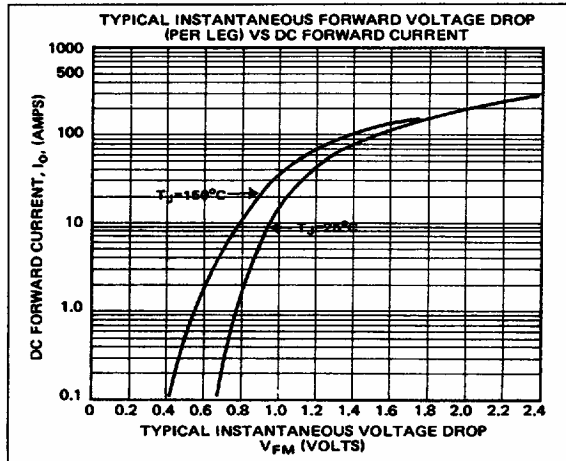


FIGURE 3

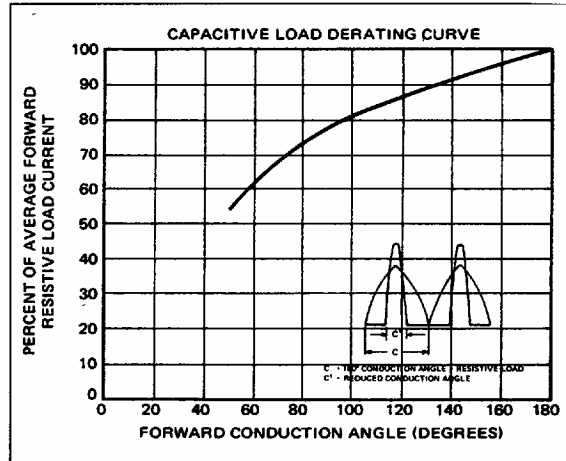


FIGURE 4

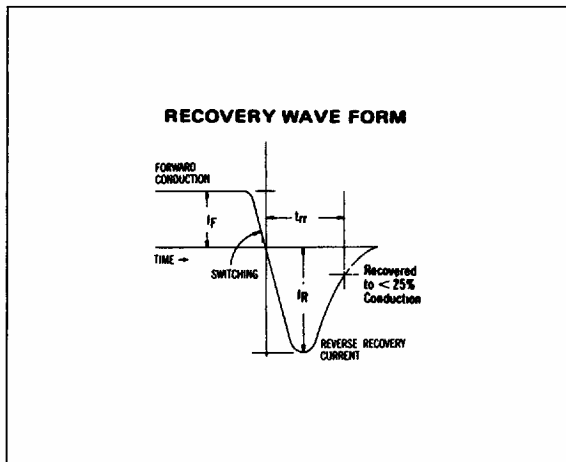


FIGURE 5